**Product data sheet** 

### 1 General description

The 74LV03 is a low-voltage Si-gate CMOS device and is pin and function compatible with 74HC/HCT03.

The 74LV03 provides the 2-input NAND function.

The 74LV03 has open-drain N-transistor outputs, which are not clamped by a diode connected to  $V_{CC}$ . In the OFF-state, i.e., when one input is LOW, the output may be pulled to any voltage between GND and  $V_{O(max)}$ . This allows the device to be used as a LOW-to-HIGH or HIGH-to-LOW level shifter. For digital operation and OR-tied output applications, these devices must have a pull-up resistor to establish a logic HIGH level.

#### 2 Features and benefits

- Wide operating voltage: 1.0 V to 5.5 V
- Optimized for low voltage applications: 1.0 V to 3.6 V
- Accepts TTL input levels between V<sub>CC</sub> = 2.7 V and V<sub>CC</sub> = 3.6 V
- Typical V<sub>OLP</sub> (output ground bounce) < 0.8 V @ V<sub>CC</sub> = 3.3 V, T<sub>amb</sub> = 25 °C
- Typical V<sub>OHV</sub> (output V<sub>OH</sub> undershoot) > 2 V @ V<sub>CC</sub> = 3.3 V, T<sub>amb</sub> = 25 °C
- Level shifter capability
- · ESD protection:
  - HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C

# 3 Ordering information

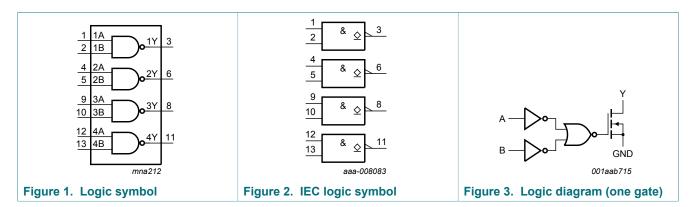
**Table 1. Ordering information** 

Type number	Package			
	Temperature range	Name	Description	Version
74LV03D	-40 °C to + 125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1



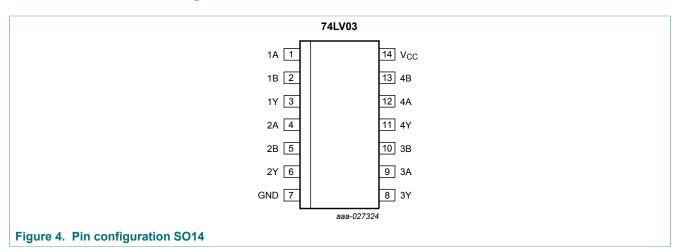
**Quad 2-input NAND gate** 

# 4 Functional diagram



## 5 Pinning information

### 5.1 Pinning



### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 2A, 3A, 4A	1, 4, 9, 12	data input
1B, 2B, 3B, 4B	2, 5, 10, 13	data input
1Y, 2Y, 3Y, 4Y	3, 6, 8, 11	data output
GND	7	ground (0 V)
V <sub>cc</sub>	14	supply voltage

**Quad 2-input NAND gate** 

# **Functional description**

Table 3. Function table <sup>[1]</sup>

Input		Output
nA	nB	nY
L	L	Z
L	Н	Z
Н	L	Z
Н	Н	L

H = HIGH voltage level;

## **Limiting values**

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 \text{ V or } V_1 > V_{CC} + 0.5 \text{ V}$ [1]	-	±20	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$ [1]	-	±50	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	50	mA
I <sub>GND</sub>	ground current		-50	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$ [2]	-	500	mW

The input and output voltage ratings may be exceeded if the input and output current ratings are observed.  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

L = LOW voltage level;

Z = high-impedance OFF-state.

<sup>[1]</sup> [2]

**Quad 2-input NAND gate** 

# 8 Recommended operating conditions

#### Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>CC</sub>	supply voltage	[1]	1.0	3.3	5.5	V
VI	input voltage		0	-	V <sub>CC</sub>	V
Vo	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 1.0 V to 2.0 V	-	-	500	ns/V
		V <sub>CC</sub> = 2.0 V to 2.7 V	-	-	200	ns/V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	100	ns/V
		V <sub>CC</sub> = 3.6 V to 5.5 V	-	-	50	ns/V

<sup>[1]</sup> The static characteristics are guaranteed from  $V_{CC}$  = 1.2 V to  $V_{CC}$  = 5.5 V, but LV devices are guaranteed to function down to  $V_{CC}$  = 1.0 V (with input levels GND or  $V_{CC}$ ).

## 9 Static characteristics

#### **Table 6. Static characteristics**

Voltages are referenced to GND (ground = 0 V).

Symbol Parameter		Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 1.2 V	0.9	-	-	0.9	-	V
	input voltage	V <sub>CC</sub> = 2.0 V	1.4	-	-	1.4	-	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	0.7V <sub>CC</sub>	-	-	0.7V <sub>CC</sub>	-	V
$V_{IL}$	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.3	-	0.3	V
	input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.6	-	0.6	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.3V <sub>CC</sub>	-	0.3V <sub>CC</sub>	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 1.2 V	-	0	-	-	-	V
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 2.0 V	-	0	0.2	-	0.2	V
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 2.7 V	-	0	0.2	-	0.2	V
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 3.0 V	-	0	0.2	-	0.2	V
		I <sub>O</sub> = 100 μA; V <sub>CC</sub> = 4.5 V	-	0	0.2	-	0.2	V
		I <sub>O</sub> = 6 mA; V <sub>CC</sub> = 3.0 V	-	0.25	0.40	-	0.50	V
		I <sub>O</sub> = 12 mA; V <sub>CC</sub> = 4.5 V	-	0.35	0.55	-	0.65	V
I <sub>I</sub>	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	1.0	μA

74LV03

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### **Quad 2-input NAND gate**

Symbol	Parameter Conditions		-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
I <sub>OZ</sub>	OFF-state output current	per input pin; $V_{CC}$ = 2.0 V to 3.6 V; $V_{I}$ = $V_{IL}$ ; $V_{O}$ = $V_{CC}$ or GND; other inputs at $V_{CC}$ or GND	-	-	±5.0	-	±10	μA
		per input pin; $V_{CC}$ = 2.0 V to 3.6 V; $^{[2]}$ $V_I$ = $V_{IL}$ ; $V_O$ = 6.0 V; other inputs at $V_{CC}$ or GND	-	-	±10.0	-	±20	μA
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$	-	-	20.0	-	40	μΑ
ΔI <sub>CC</sub>	additional supply current	per input; $V_I = V_{CC} - 0.6 \text{ V}$ ; $V_{CC} = 2.7 \text{ V}$ to 3.6 V	-	-	500	-	850	μΑ
C <sub>I</sub>	input capacitance		-	3.5	-	-	-	pF

### 10 Dynamic characteristics

### Table 7. Dynamic characteristics

GND = 0 V; For test circuit see Figure 6.

Symbol Parameter		Conditions	-40 °C to +85 °C			-40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	
t <sub>pd</sub>	propagation	nA, nB to nY; see Figure 5						
	delay	V <sub>CC</sub> = 1.2 V	-	50	-	-	-	ns
		V <sub>CC</sub> = 2.0 V	-	17	26	-	31	ns
		V <sub>CC</sub> = 2.7 V	-	13	19	-	23	ns
		$V_{CC} = 3.3 \text{ V}; C_L = 15 \text{ pF}$	-	8	-	-	-	ns
		V <sub>CC</sub> = 3.0 V to 3.6 V [3]	-	10	16	-	19	ns
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	13	-	16	ns
C <sub>PD</sub>	power dissipation capacitance	$C_L = 0 \text{ pF}; R_L = \infty \Omega;$ $V_I = \text{GND to } V_{CC}$ [4]	-	4	-	-	-	pF

All typical values are measured at  $T_{amb}$  = 25 °C.

 $f_i$  = input frequency in MHz,

f<sub>o</sub> = output frequency in MHz

 $C_L$  = output load capacitance in pF

V<sub>CC</sub> = supply voltage in V

N = number of inputs switching  $\Sigma(C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs}.$ 

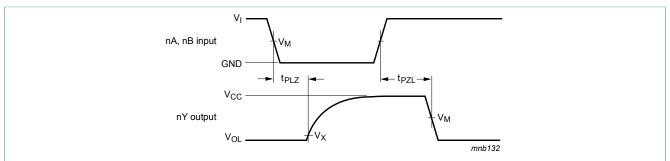
Typical values are measured at T<sub>amb</sub> = 25 °C. The maximum operating output voltage (V<sub>O(max)</sub>) is 6.0 V.

 $t_{pd}$  is the same as  $t_{PLZ}$  and  $t_{PZL}$ . Typical values are measured at nominal supply voltage ( $V_{CC}$  = 3.3 V).  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_{D}$  in  $\mu$ W).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

**Quad 2-input NAND gate** 

### 10.1 Waveforms and test circuit



Measurement points are given in Table 8

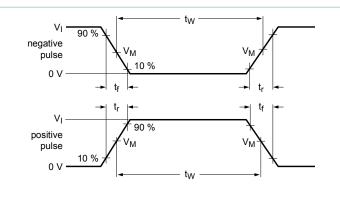
 $V_{\text{OL}}$  is a typical voltage output level that occurs with the output load.

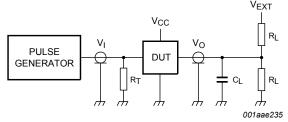
Figure 5. Inputs nA and nB to output nY propagation delay times

Table 8. Measurement points

Supply voltage	Input	Output		
V <sub>CC</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>M</sub>	
≤ 2.7 V	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	0.5 × V <sub>CC</sub>	
2.7 V to 3.6 V	1.5 V	V <sub>OL</sub> + 0.3 V	1.5 V	
≥ 4.5 V	0.5 × V <sub>CC</sub>	V <sub>OL</sub> + 0.1 V	0.5 × V <sub>CC</sub>	

### **Quad 2-input NAND gate**





Test data is given in Table 9

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

 $V_{EXT}$  = External voltage for measuring switching times.

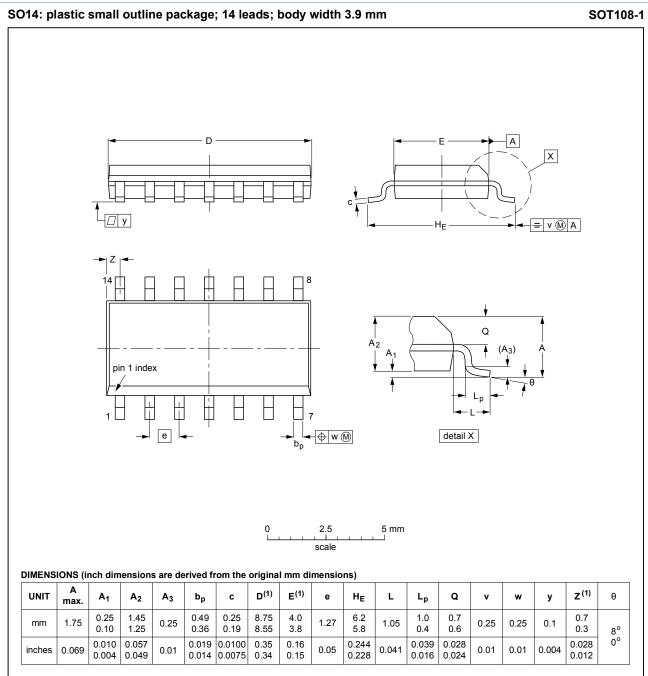
Figure 6. Test circuit for measuring switching times

Table 9. Test data

Supply voltage	Input		Load	V <sub>EXT</sub>	
V <sub>CC</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLZ</sub> , t <sub>PZL</sub>
≤ 2.7 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	1 kΩ	2 × V <sub>CC</sub>
2.7 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	1 kΩ	2 × V <sub>CC</sub>
≥ 4.5 V	V <sub>CC</sub>	≤ 2.5 ns	50 pF	1 kΩ	2 × V <sub>CC</sub>

**Quad 2-input NAND gate** 

# 11 Package outline



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE	OUTLINE REFERENCES				EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	1990E DATE	
SOT108-1	076E06	MS-012				<del>99-12-27</del> 03-02-19	

Figure 7. Package outline SOT108-1 (SO14)

74LV03

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Quad 2-input NAND gate

### 12 Abbreviations

#### Table 10. Abbreviations

Acronym	Description	
CMOS	omplementary Metal-Oxide Semiconductor	
DUT	Device Under Test	
TTL	Transistor-Transistor Logic	

# 13 Revision history

### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LV03 v.4	20170831	Product data sheet	-	74LV03 v.3		
Modifications:	<ul> <li>The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia.</li> <li>Legal texts have been adapted to the new company name where appropriate.</li> </ul>					
74LV03 v.3	20030303	Product data sheet	ECN 853-1963 29494	74LV03 v.2		
Modifications:	<ul> <li>Deleted DIL, SSOP and TSSOP package ordering and package outlines (discontinued options).</li> <li>Corrected power dissipation formula.</li> </ul>					
74LV03 v.2	19980420	Product specification	ECN 853-1963 19257	74LV03 v.1		
74LV03 v.1	19970328	Product specification	-	-		

**Quad 2-input NAND gate** 

### 14 Legal information

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- The term 'short data sheet' is explained in section "Definitions". [2] [3]
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### Quad 2-input NAND gate

### **Contents**

1	General description	1
2	Features and benefits	
3	Ordering information	1
4	Functional diagram	2
5	Pinning information	2
5.1	Pinning	2
5.2	Pin description	
6	Functional description	
7	Limiting values	
8	Recommended operating conditions	
9	Static characteristics	
10	Dynamic characteristics	
10.1	Waveforms and test circuit	
11	Package outline	
12	Abbreviations	
13	Revision history	
14	Legal information	10

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